



Title: Multi-Configurable Independently Double-Gated MOSFET
Inventors: Douglas R. Hackler, Sr. and Stephen A. Parke
Docket No.: 51889/2

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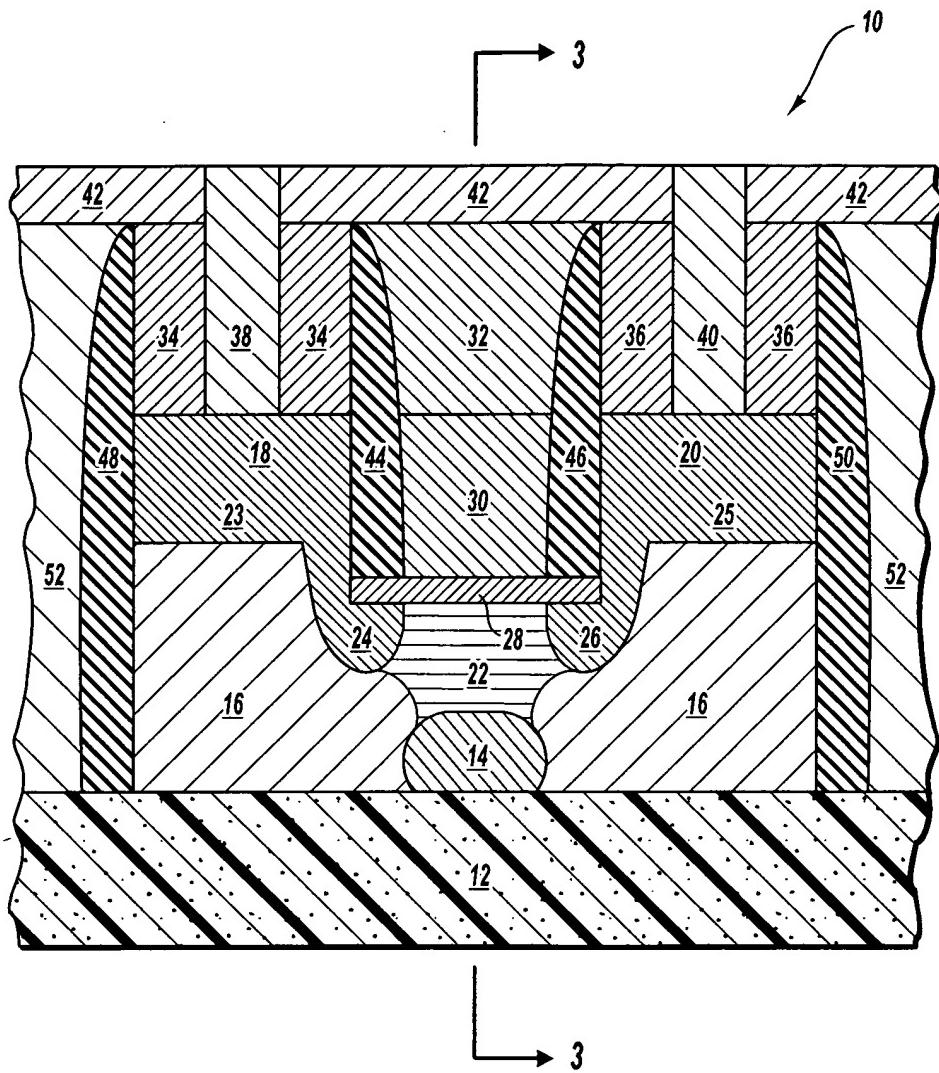


Fig. 1

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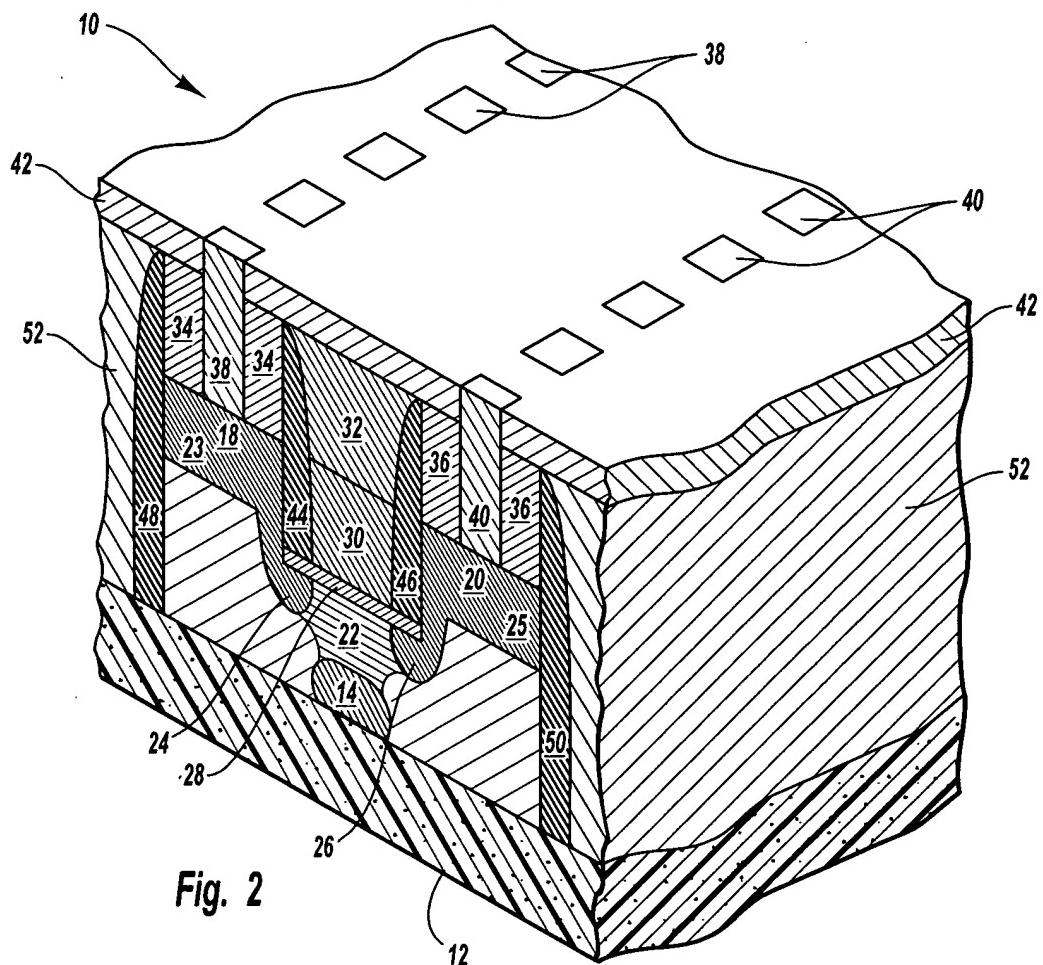


Fig. 2

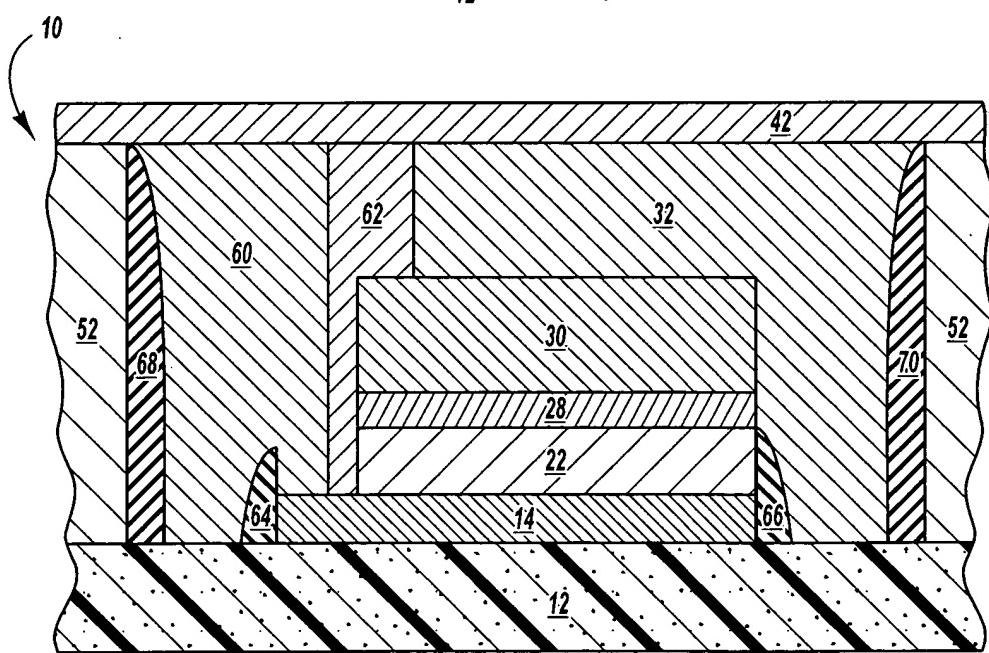


Fig. 3

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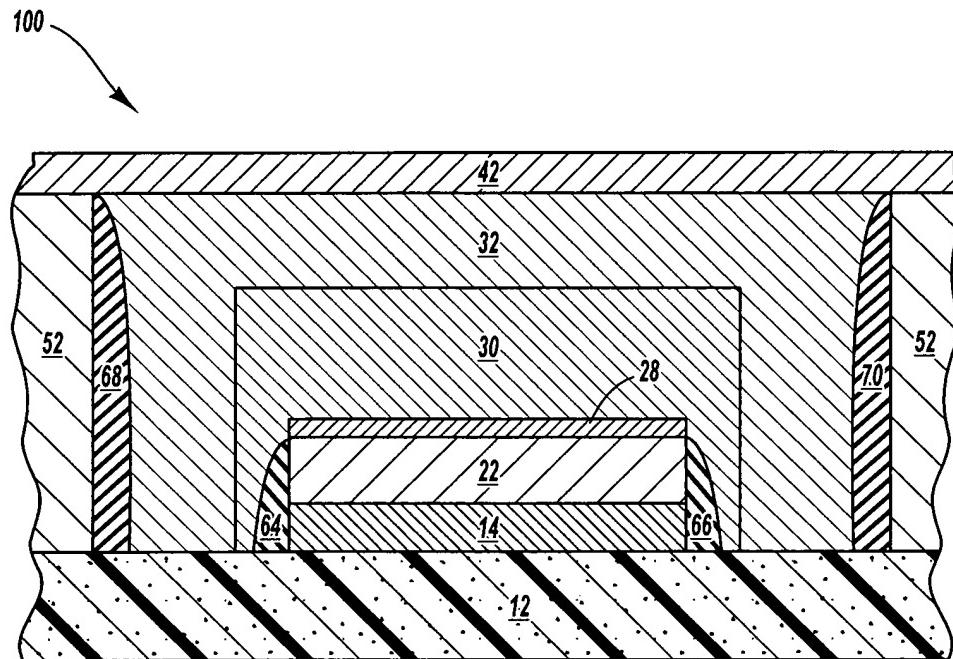


Fig. 4

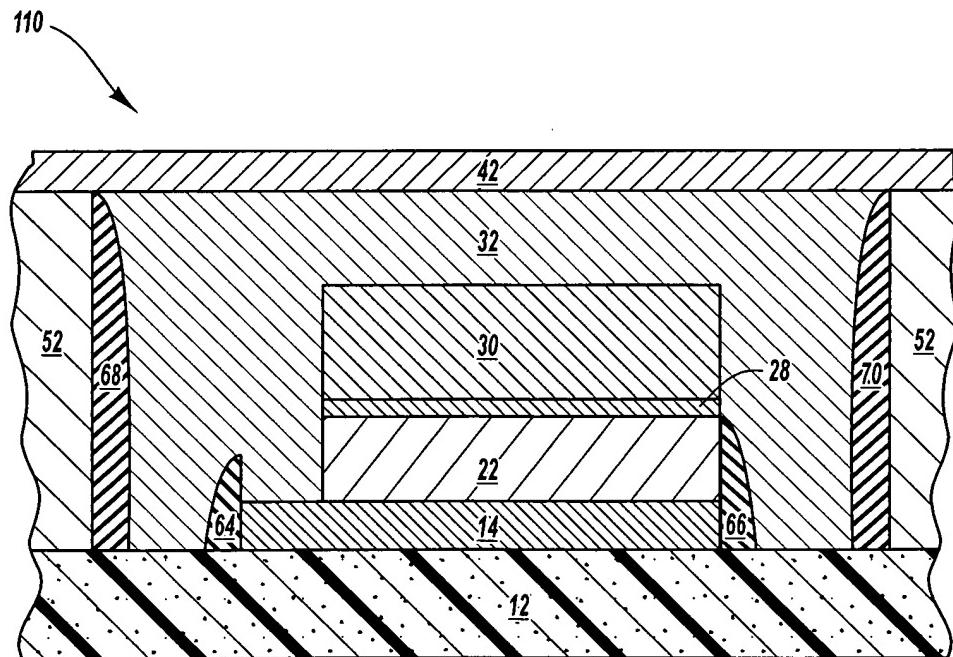


Fig. 5

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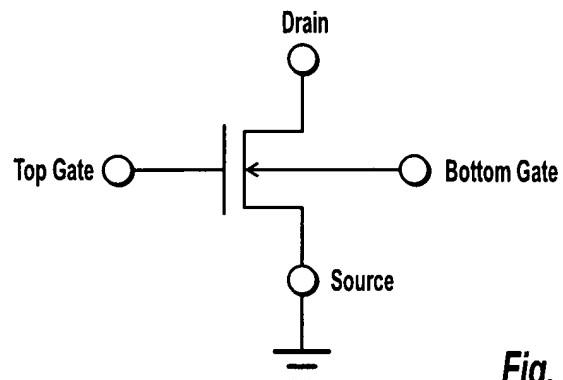


Fig. 6

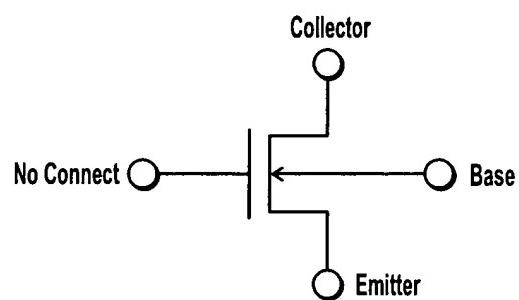


Fig. 7

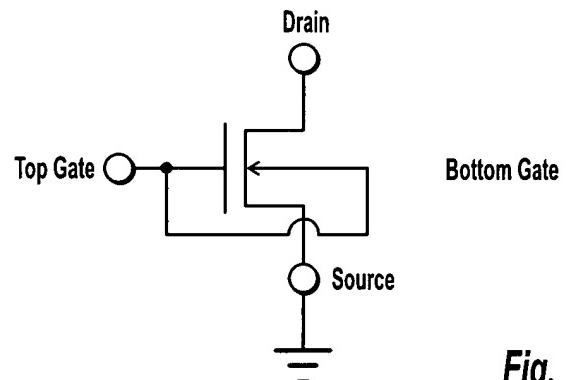


Fig. 8

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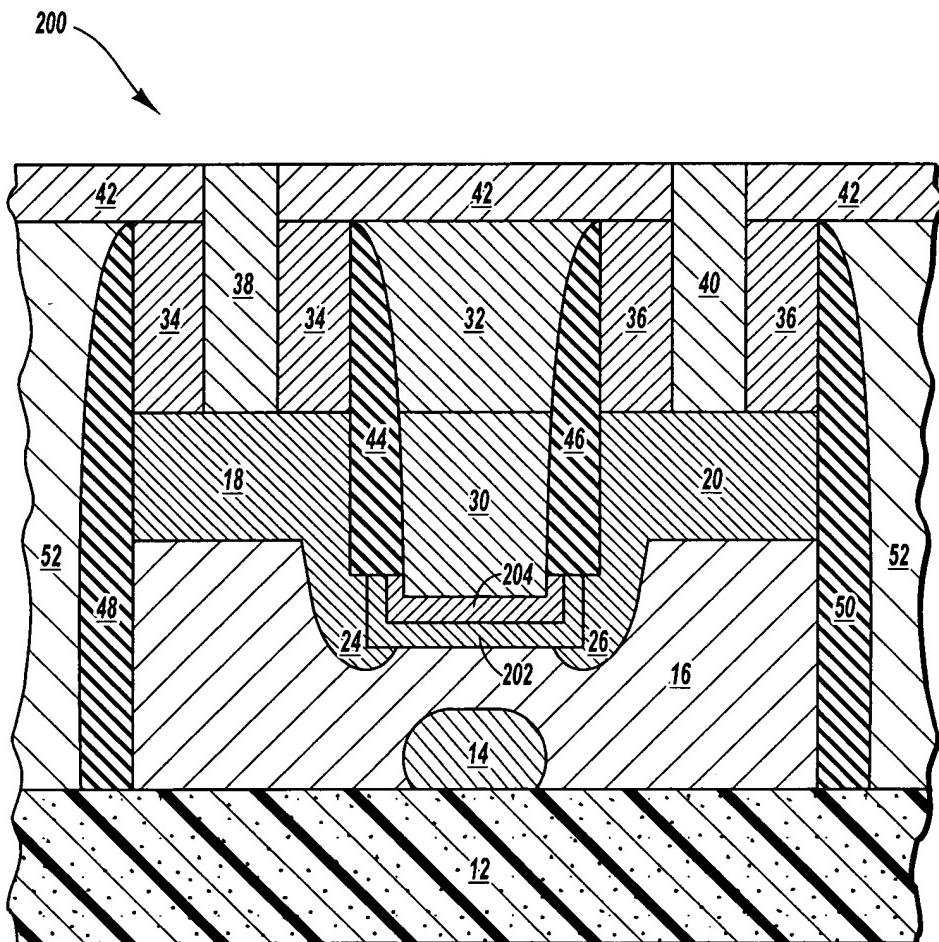


Fig. 9

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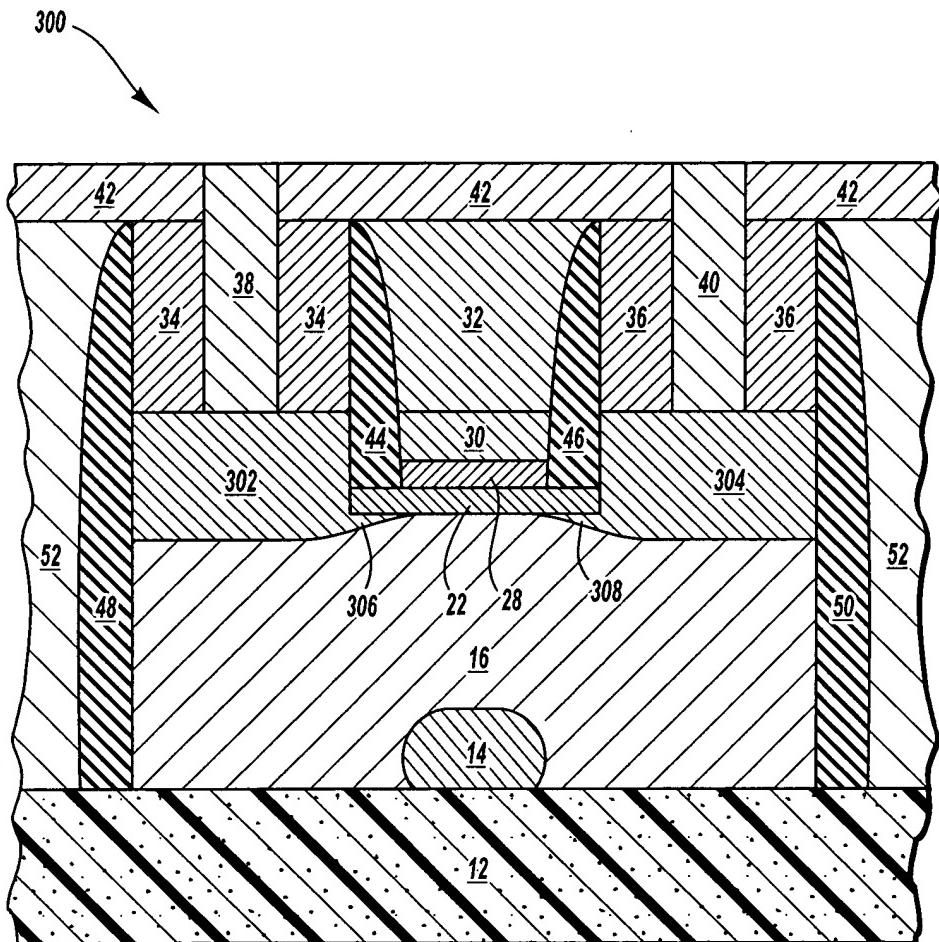


Fig. 10

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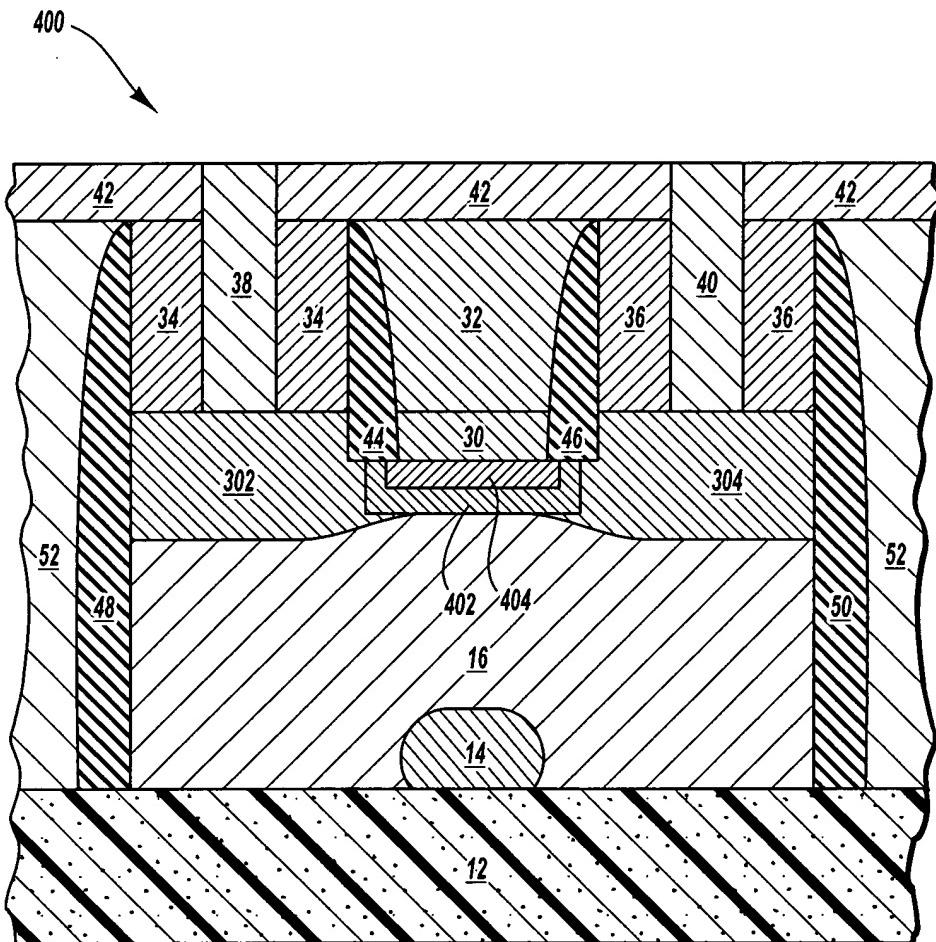


Fig. 11

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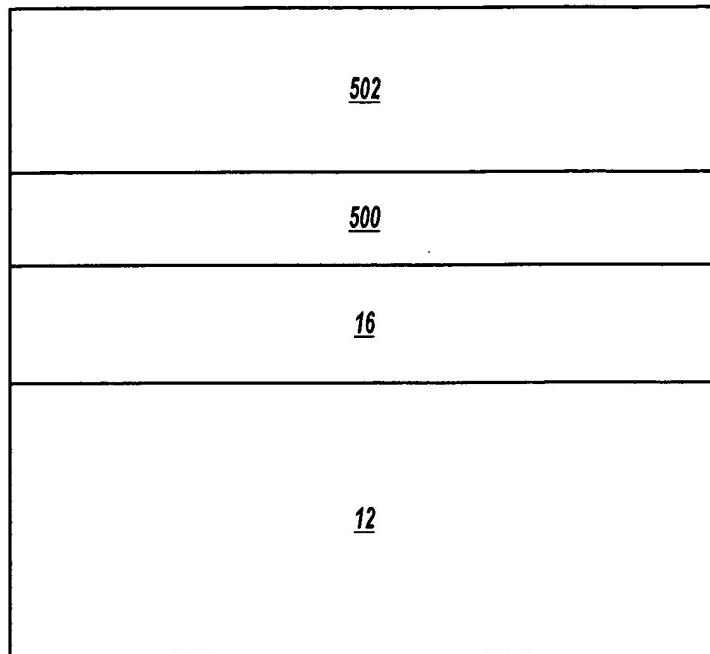


Fig. 12

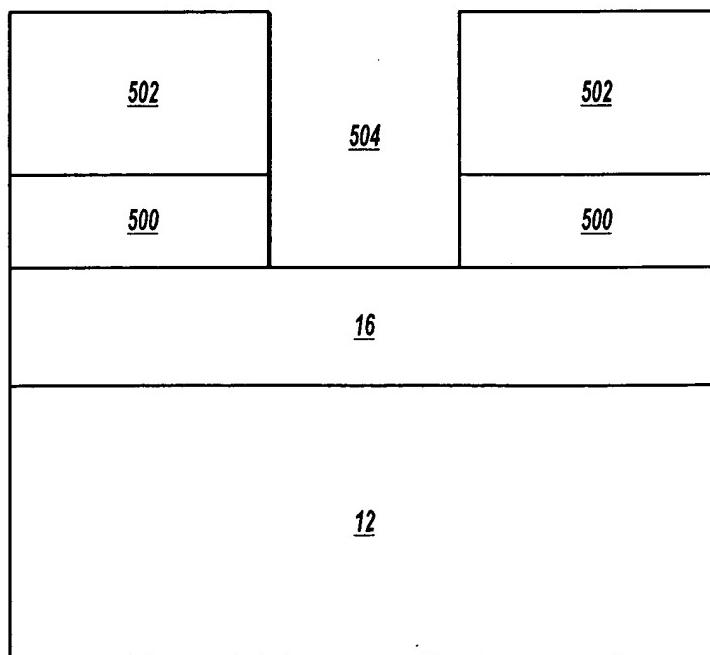


Fig. 13

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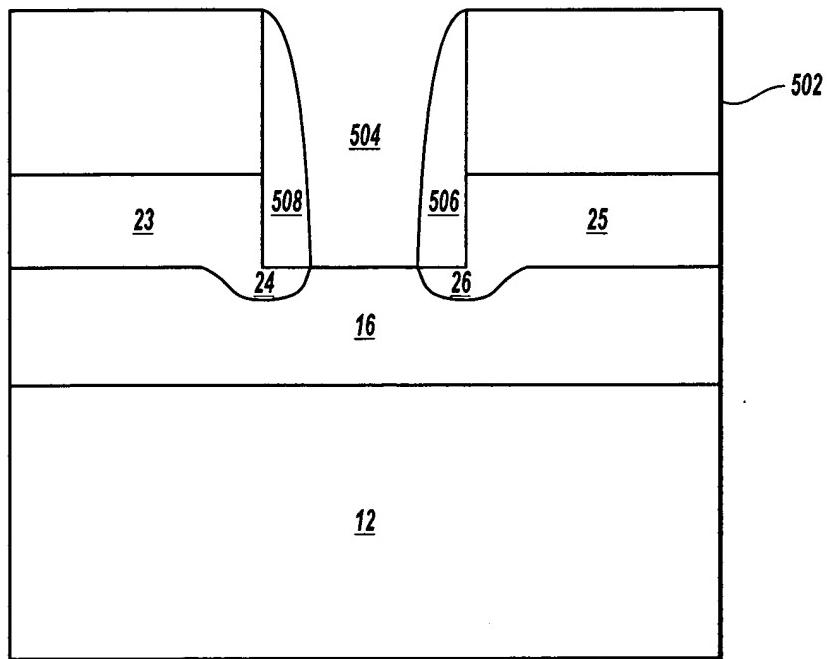


Fig. 14

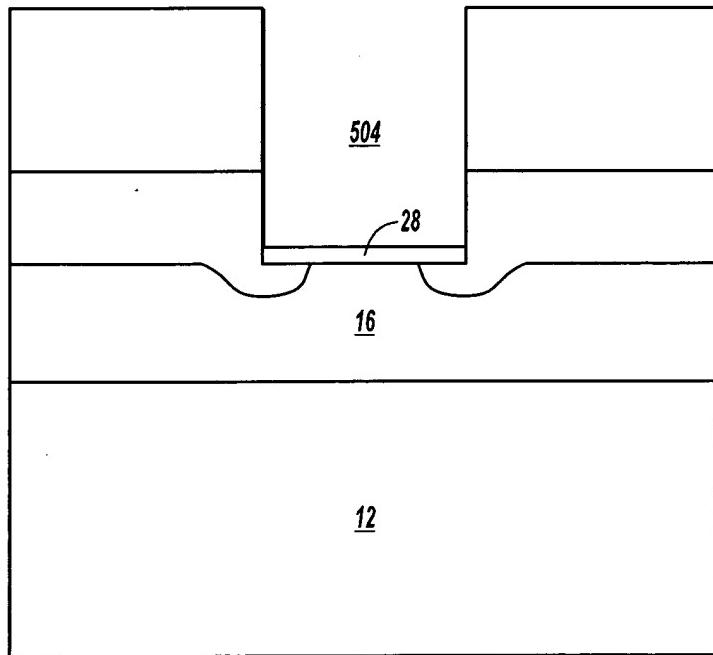


Fig. 15

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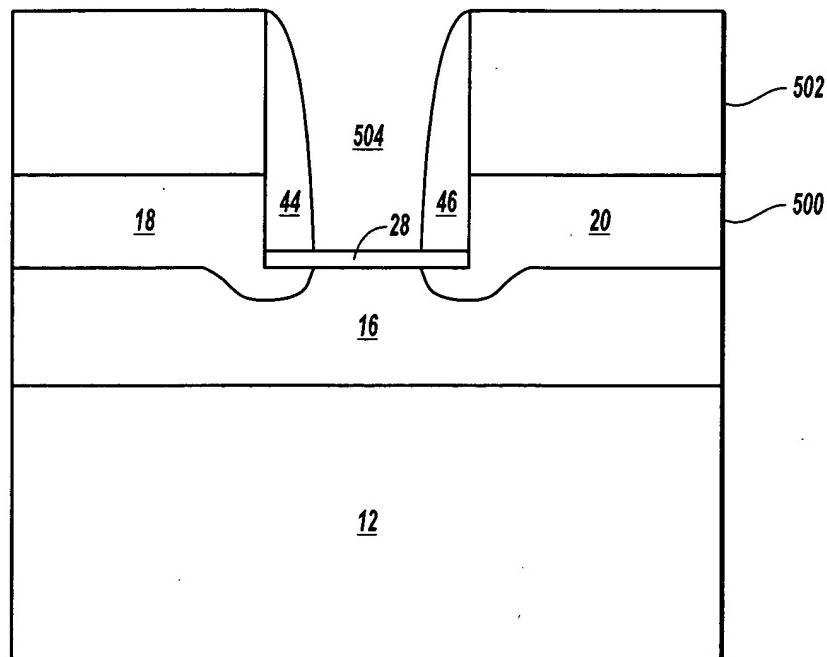


Fig. 16

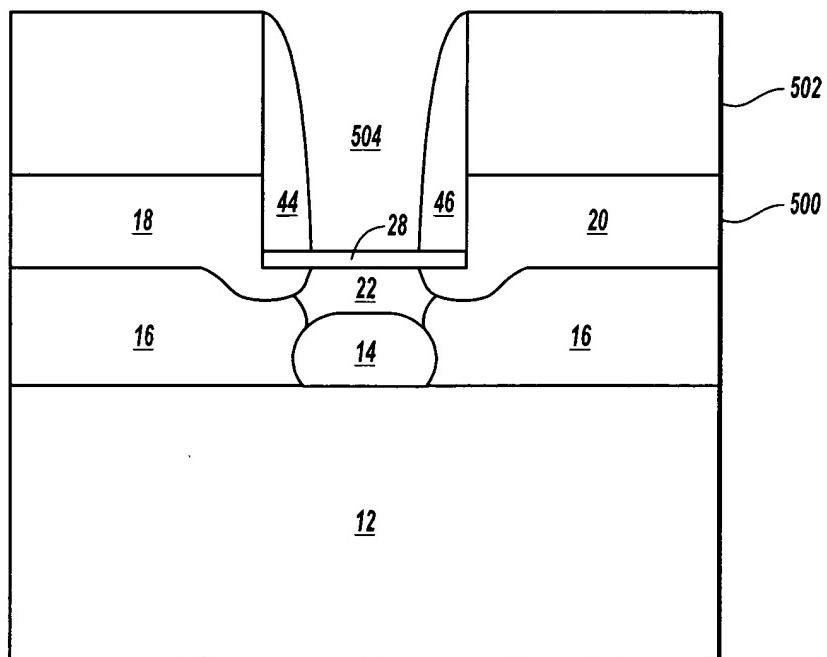


Fig. 17

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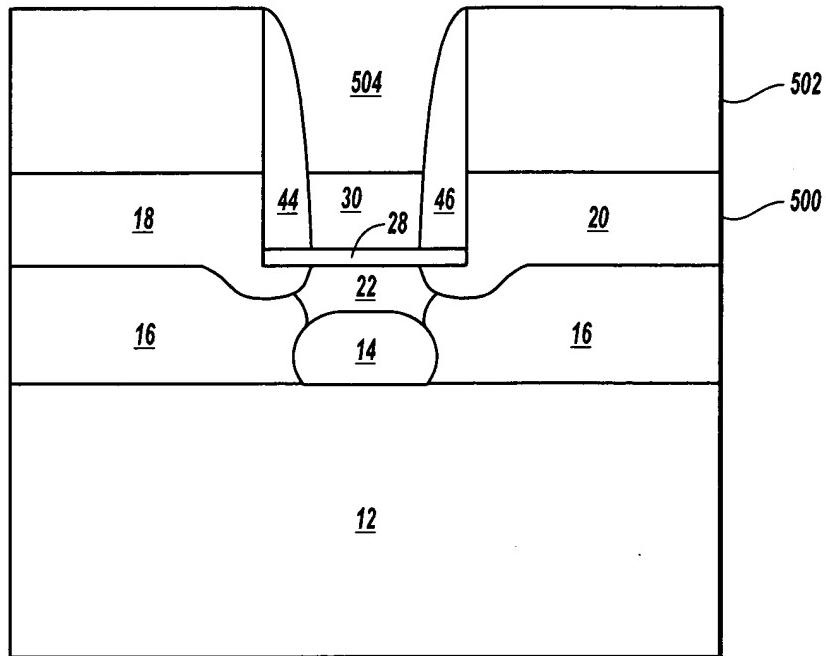


Fig. 18

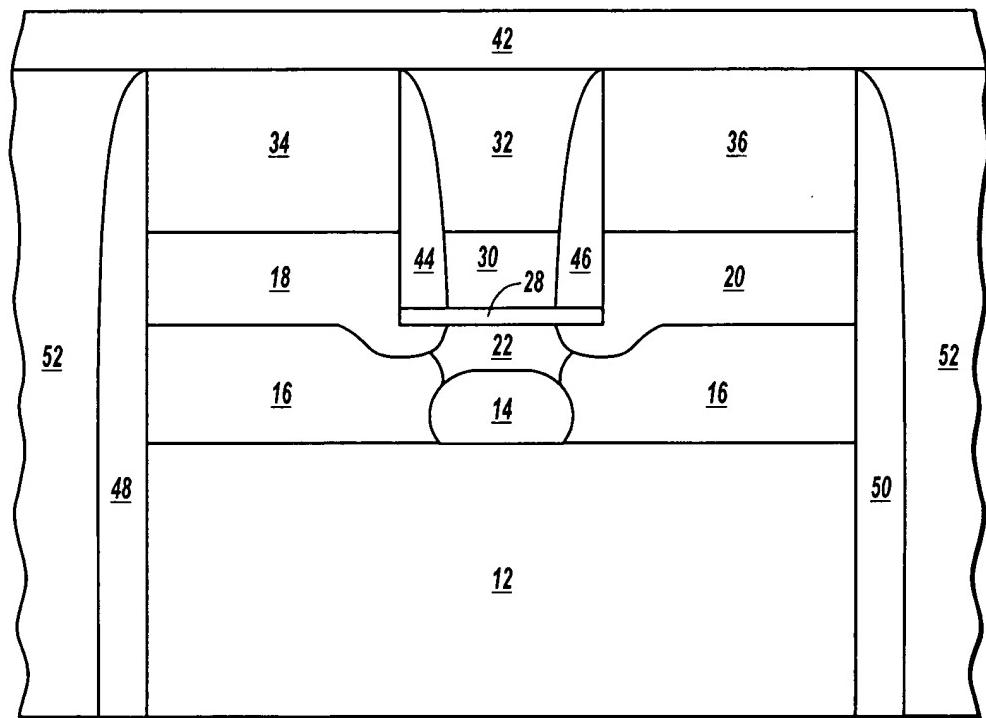


Fig. 19

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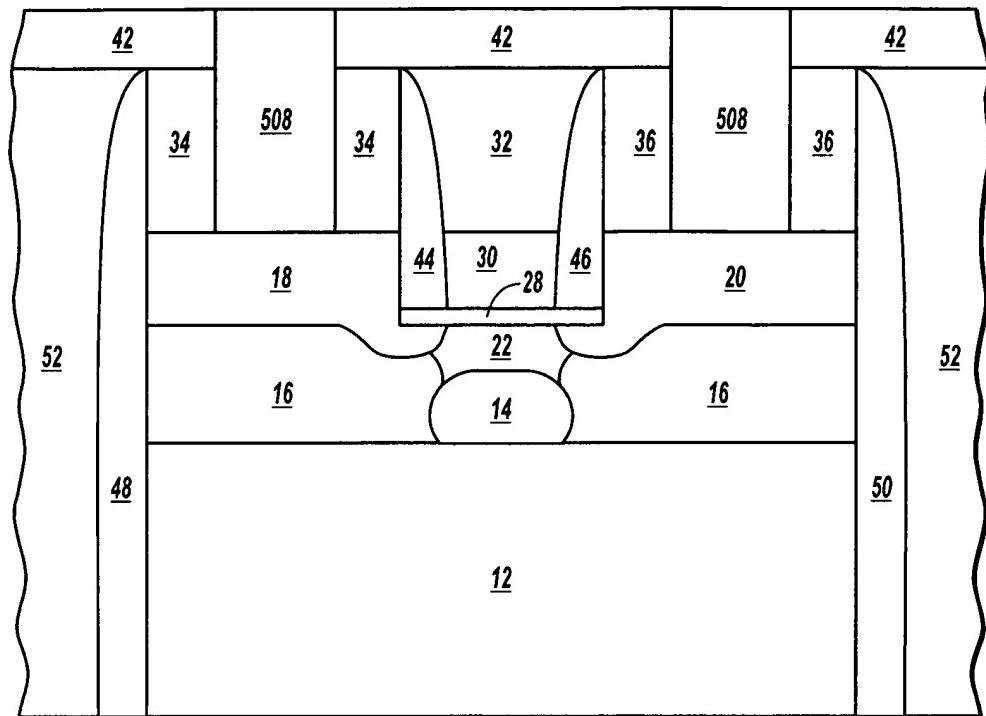


Fig. 20